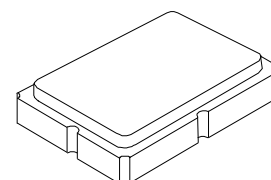


RO3164A/A-1

868.35 MHz SAW Resonator



SM5035-4

- **Designed for European 868.35 MHz SRD Transmitters**
- **Very Low Series Resistance**
- **Quartz Stability**
- **Surface-mount Ceramic Case**

The RO3164A is a one-port surface-acoustic-wave (SAW) resonator packaged in a surface-mount ceramic case. It provides reliable, fundamental-mode quartz frequency stabilization of fixed-frequency transmitters operating at 868.35 MHz. The RO3164A is designed specifically for remote control and wireless security SRD transmitters operating under ETSI EN 300 220-2.

Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation	+5	dBm
DC Voltage Between Terminals	±30	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature, 10 seconds / 5 cycles maximum	260	°C

Electrical Characteristics

Characteristic	Sym	Notes	Minimum	Typical	Maximum	Units
Frequency, +25 °C	RO3164A RO3164A-1	f_C	868.150 868.200		868.550 868.500	MHz
Tolerance from 868.35 MHz	RO3164A RO3164A-1	Δf_C			±200 ±150	kHz
Insertion Loss	IL	2,5,6		1.3	2.0	dB
Quality Factor	Unloaded Q 50 Ω Loaded Q	Q_U Q_L	5,6,7	6600 800		
Temperature Stability	Turnover Temperature Turnover Frequency Frequency Temperature Coefficient	T_O f_O FTC	6,7,8	10 f_C 0.032	25 40	°C kHz ppm/°C ²
Frequency Aging	Absolute Value during the First Year	fA	1	<±10		ppm/yr
DC Insulation Resistance between Any Two Terminals		5	1.0			M Ω
RF Equivalent RLC Model	Motional Resistance Motional Inductance Motional Capacitance Shunt Static Capacitance	R_M L_M C_M C_O	5, 6, 7, 9 5, 6, 9	13.8 16.8 2.0 1.8		Ω μ H fF pF
Test Fixture Shunt Inductance	L_{TEST}	2, 7		18.3		nH
Lid Symbolization (in addition to Lot and/or Date Codes)	RO3164A: 660, RO3164A-1: 780: 868 // YYWWS					



CAUTION: Electrostatic Sensitive Device. Observe precautions for handling.

NOTES:

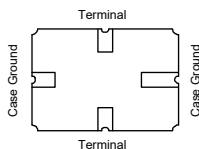
1. Frequency aging is the change in f_c with time and is specified at +65 °C or less. Aging may exceed the specification for prolonged temperatures above +65 °C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
2. The center frequency, f_c , is measured at the minimum insertion loss point, IL_{MIN} , with the resonator in the 50 Ω test system ($VSWR \leq 1.2:1$). The shunt inductance, L_{TEST} , is tuned for parallel resonance with C_O at f_c . Typically, $f_{OSCILLATOR}$ or $f_{TRANSMITTER}$ is approximately equal to the resonator f_c .
3. One or more of the following United States patents apply: 4,454,488 and 4,616,197.
4. Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
5. Unless noted otherwise, case temperature $T_C = +25 \pm 2$ °C.
6. The design, manufacturing process, and specifications of this device are subject

to change without notice.

7. Derived mathematically from one or more of the following directly measured parameters: f_c , IL , 3 dB bandwidth, f_c versus T_C , and C_O .
8. Turnover temperature, T_O , is the temperature of maximum (or turnover) frequency, f_O . The nominal frequency at any case temperature, T_C , may be calculated from: $f = f_O [1 - FTC (T_O - T_C)^2]$. Typically *oscillator* T_O is approximately equal to the specified *resonator* T_O .
9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_O is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can be calculated as: $C_P \approx C_O - 0.05$ pF.

Electrical Connections

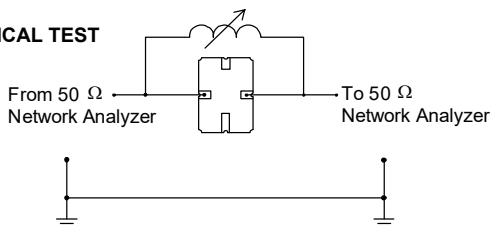
The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit.



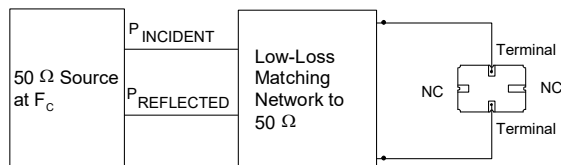
Typical Test Circuit

The test circuit inductor, L_{TEST} , is tuned to resonate with the static capacitance, C_O , at f_c .

ELECTRICAL TEST

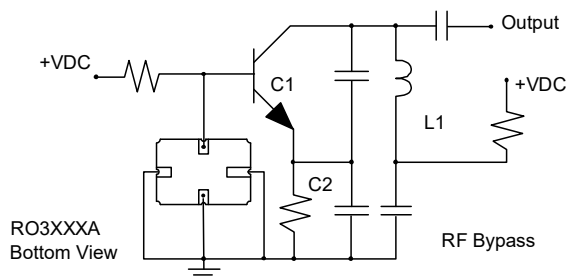


POWER TEST



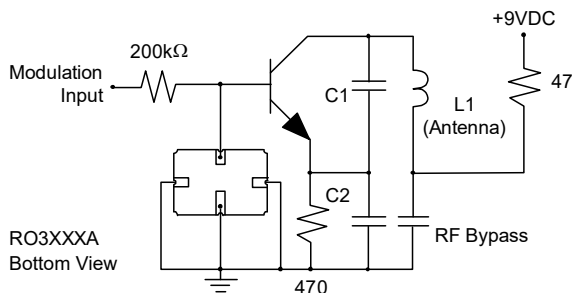
$$CW \text{ RF Power Dissipation} = P_{INCIDENT} - P_{REFLECTED}$$

Typical Local Oscillator Applications

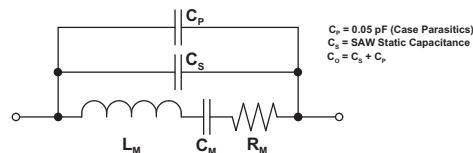


Typical Application Circuits

Typical Low-Power Transmitter Application



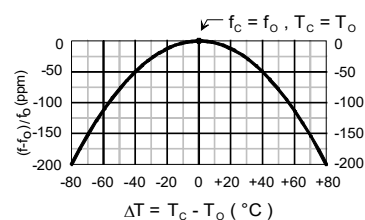
Equivalent RLC Model



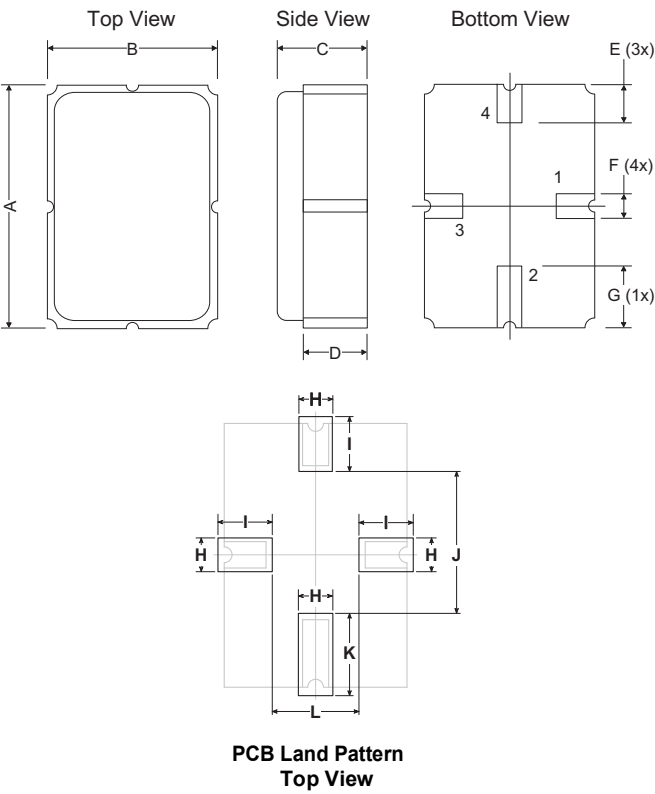
$C_P = 0.05$ pF (Case Parasitics)
 C_S = SAW Static Capacitance
 $C_O = C_S + C_P$

Temperature Characteristics

The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.



Case



Dimensions	Millimeters			Inches		
	Min	Nom	Max	Min	Nom	Max
A	4.87	5.00	5.13	0.191	0.196	0.201
B	3.37	3.50	3.63	0.132	0.137	0.142
C	1.45	1.53	1.60	0.057	0.060	0.062
D	1.35	1.43	1.50	0.040	0.057	0.059
E	0.67	0.80	0.93	0.026	0.031	0.036
F	0.37	0.50	0.63	0.014	0.019	0.024
G	1.07	1.20	1.33	0.042	0.047	0.052
H	-	1.04	-	-	0.041	-
I	-	1.46	-	-	0.058	-
J	-	3.01	-	-	0.119	-
K	-	1.44	-	-	0.057	-
L	-	1.92	-	-	0.076	-